## NSN 5961-01-038-2059

No Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-038-2059 **Inclosure Material:** Glass and metal **Overall Length:** 0.400 inches **Overall Diameter:** 0.185 inches **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 12.0 regulator voltage **Current Rating Per Characteristic:** 200.00 milliamperes repetitive peak forward current **Power Rating Per Characteristic:** 6.0 watts small-signal input power, common-collector absolute **Precious Material And Location:** Body gold **Precious Material:** Gold **Test Data Document:** 36452-10815 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**